

Three Phase Rectifier Bridge Slim Version

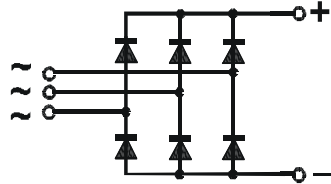
Preliminary Data Sheet

PSDS 82

$$I_{dAV} = 88 \text{ A}$$

$$V_{RRM} = 800-1800 \text{ V}$$

V_{RSM} V_{DSM} (V)	V_{RRM} V_{DRM} (V)	Type
800	800	PSDS 82/08
1200	1200	PSDS 82/12
1400	1400	PSDS 82/14
1600	1600	PSDS 82/16
1800	1800	PSDS 82/18



- Low profile (overall height: 17 mm)
- Package with screw terminals
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL release applied, RoHS conform

Applications

- Supplies for DC power equipment
- Input rectifier for PWM inverter
- Battery DC power supplies
- Field supply for DC motors
- etc.

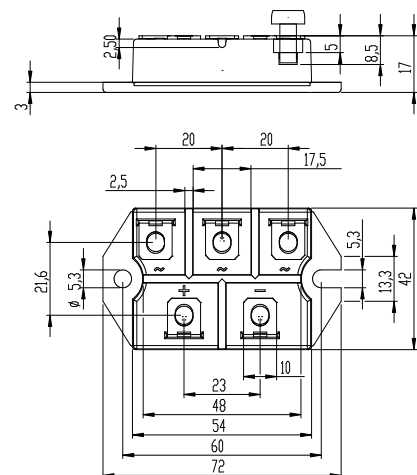
Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability

Package style and outline

Dimensions in mm (1mm = 0.0394")

Max. allowed screw-in depth: 8.5 mm



Symbol	Test Conditions	Maximum Ratings
I_{dAVM}	$T_C = 110^\circ \text{C}$, (per module)	88 A
I_{FSM}	$T_{VJ} = 45^\circ \text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	750 A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	820 A
	$T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine	670 A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	740 A
$\int i^2 dt$	$T_{VJ} = 45^\circ \text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	2800 A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	2800 A ² s
	$T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine	2250 A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	2250 A ² s
T_{VJ}		-40... + 150 °C
T_{VJM}		150 °C
T_{stg}		-40... + 125 °C
V_{ISOL}	50/60 Hz, RMS $t = 1 \text{ min}$	2500 V~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000 V~
M_d	Max. mounting torque (M5)	5 Nm
	Max. terminal connection torque (M5)	5 Nm
Weight	typ.	120 g

Symbol	Test Conditions	Characteristic Value
I_R	$V_R = V_{RRM}$, $T_{VJ} = 25^\circ \text{C}$	$\leq 0.3 \text{ mA}$
	$V_R = V_{RRM}$, $T_{VJ} = T_{VJM}$	$\leq 5 \text{ mA}$
V_F	$I_F = 150 \text{ A}$, $T_{VJ} = 25^\circ \text{C}$	$\leq 1.6 \text{ V}$
V_{TO}	For power-loss calculations only	0.8 V
r_T		5 mΩ
R_{thJC}	per diode; DC current	1.1 K/W
	per module	0.183 K/W
R_{thJK}	per diode; DC current	1.52 K/W
	per module	0.253 K/W
d_s	Creeping distance on surface	10.0 mm
d_A	Creeping distance in air	9.4 mm
a	Max. allowable acceleration	50 m/s ²

Data according to IEC 60747 refer to a single diode unless otherwise stated

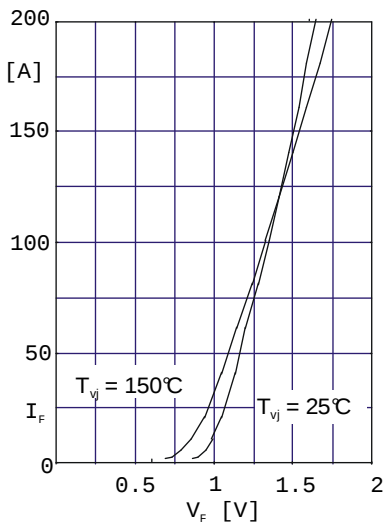


Fig. 1 Forward current versus voltage drop per diode

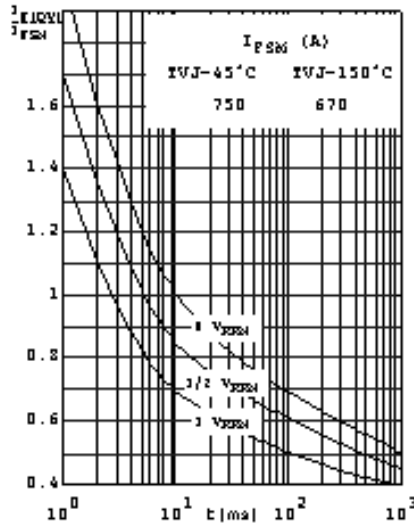


Fig. 2 Surge overload current per diode I_{FSM} ; Crest value. t: duration

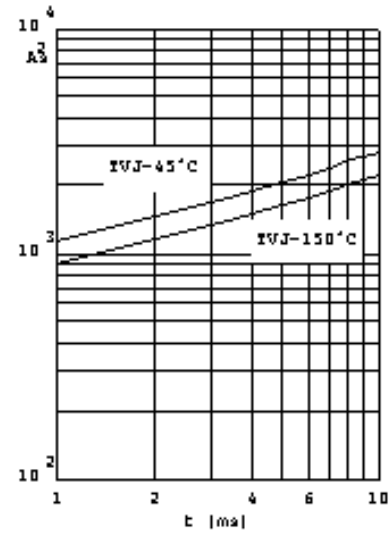


Fig. 3 $\int i^2 dt$ versus time (1-10ms) per diode (or thyristor)

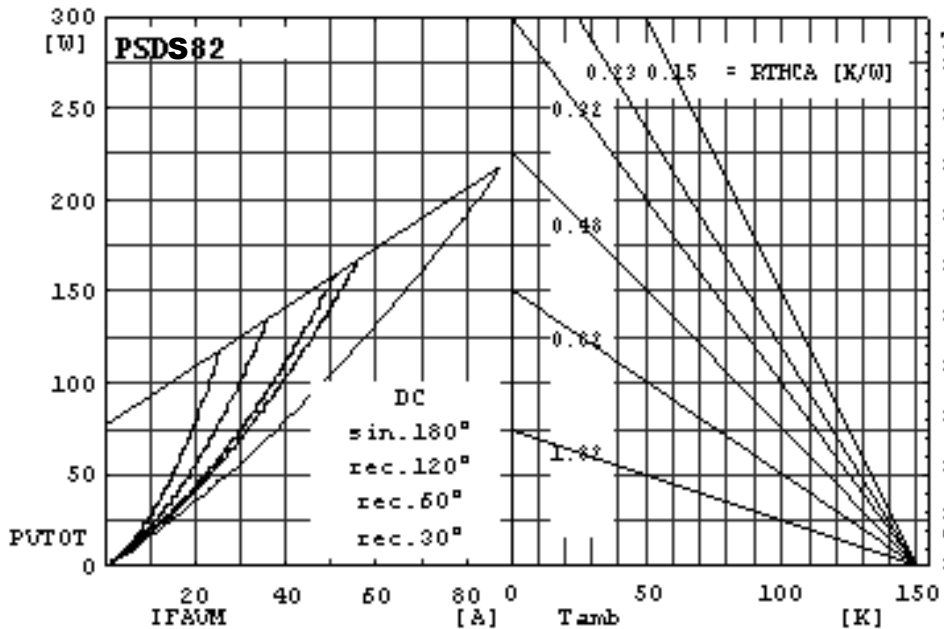


Fig. 4 Power dissipation versus direct output current and ambient temperature

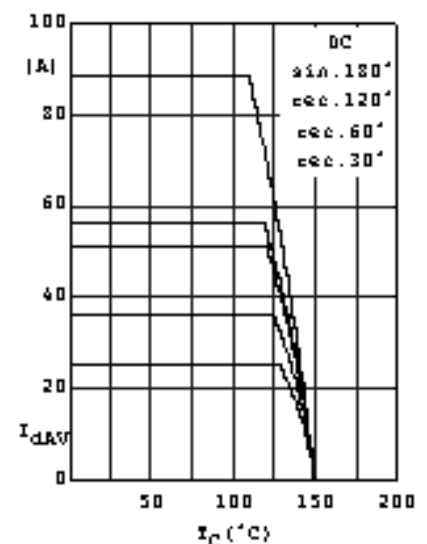


Fig. 5 Maximum forward current at case temperature

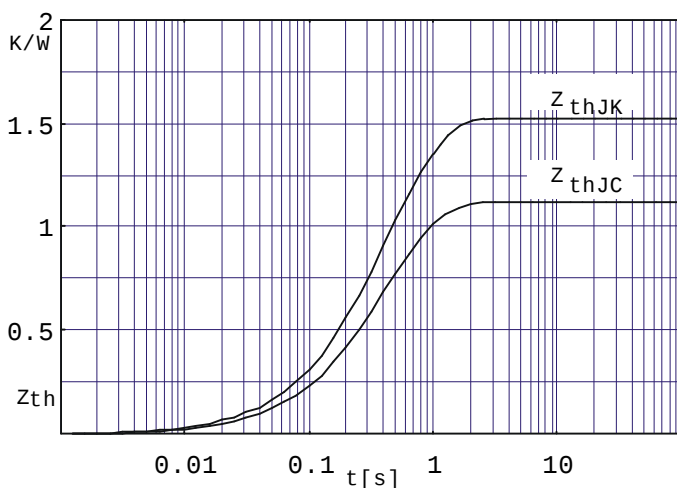


Fig. 6 Transient thermal impedance per diode (or thyristor), calculated

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